



## PJP60R190E / PJF60R190E

### 600V N-Channel Super Junction MOSFET

**Voltage**

**600 V**

**Current**

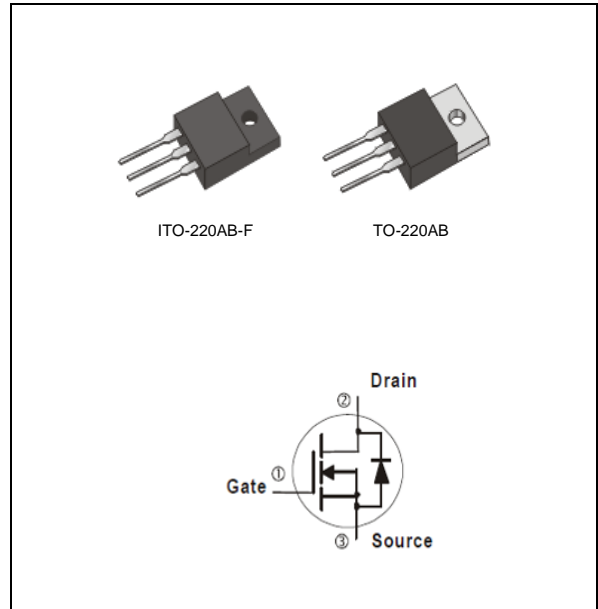
**20 A**

#### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A < 0.196\Omega$
- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### Mechanical Data

- Case : TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



#### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		$V_{DS}$	600		V
Gate-Source Voltage		$V_{GS}$	±20		
Continuous Drain Current (Note 4)	$T_C=25^\circ\text{C}$	$I_D$	20		A
	$T_C=100^\circ\text{C}$		13		
Pulsed Drain Current (Note 1)		$I_{DM}$	60		
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	231	68	W
	$T_C=100^\circ\text{C}$		92	27	
Continuous Drain Current (Note 4)	$T_A=25^\circ\text{C}$	$I_D$	2.1		A
	$T_A=70^\circ\text{C}$		1.7		
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2	1.04	W
	$T_A=70^\circ\text{C}$		1.3	0.9	
Single Pulse Avalanche Energy (Note 5)		$E_{AS}$	405		mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150		$^\circ\text{C}$
Typical Thermal Resistance (Note 4,5)		$R_{\theta JC}$	0.54	1.84	$^\circ\text{C/W}$
		$R_{\theta JA}$	62.5	120	

- Limited only By Maximum Junction Temperature



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	2.95	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$	-	0.17	0.196	$\Omega$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
Diode Forward Voltage	$V_{SD}$	$I_S=20A, V_{GS}=0V$	-	0.97	1.5	V
Transconductance	$G_{FS}$	$V_{DS}=10V, I_D=10A$	-	10	-	S
<b>Dynamic</b> (Note 6)						
Total Gate Charge	$Q_g$	$V_{DS}=300V, I_D=15A,$ $V_{GS}=10V$ (Note 2,3)	-	62	-	nC
Gate-Source Charge	$Q_{gs}$		-	8	-	
Gate-Drain Charge	$Q_{gd}$		-	34	-	
Gate Input Resistance	$R_g$	$F = 1\text{MHz}$	-	6.2	-	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1\text{MHz}$	-	1421	-	pF
Output Capacitance	$C_{oss}$		-	1427	-	
Reverse Transfer Capacitance	$C_{rss}$		-	160	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V, I_D=7.5A,$ $R_G=10\Omega$ (Note 2,3)	-	16	-	ns
Turn-On Rise Time	$t_r$		-	32	-	
Turn-Off Delay Time	$t_{d(off)}$		-	152	-	
Turn-Off Fall Time	$t_f$		-	32	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	20	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	-	-	60	
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V, I_S=20A$	-	258	-	ns
Reverse Recovery Charge	$Q_{rr}$	$di_F/dt=100A/\mu s$ (Note 2)	-	2.44	-	$\mu C$

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited.
5.  $L=70\text{mH}, I_{AS}=3.4A, V_{DD}=50V, R_G=25\text{ ohm}$ , Starting  $T_J=25^\circ\text{C}$ .
6. Guaranteed by design, not subject to production testing.



# PJP60R190E / PJF60R190E

## TYPICAL CHARACTERISTIC CURVES

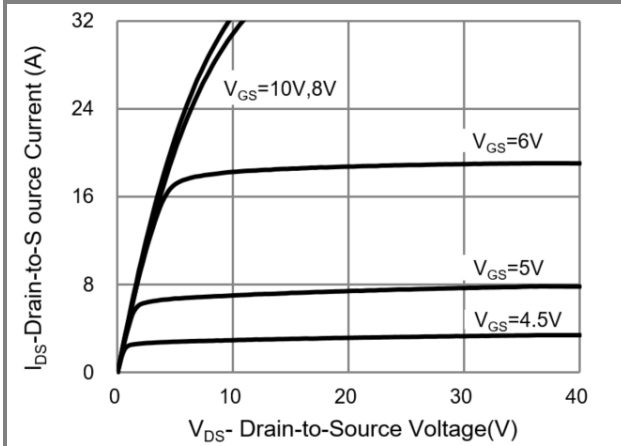


Fig.1 Output Characteristics

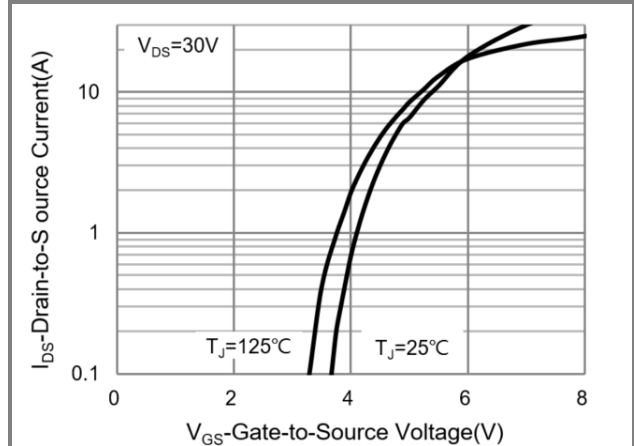


Fig.2 Transfer Characteristics

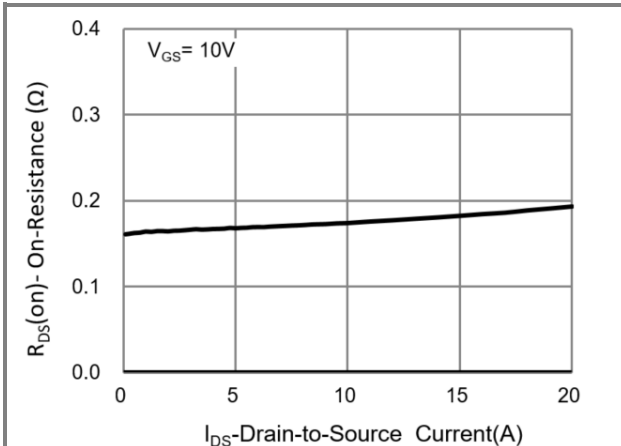


Fig.3 On-Resistance vs. Drain Current

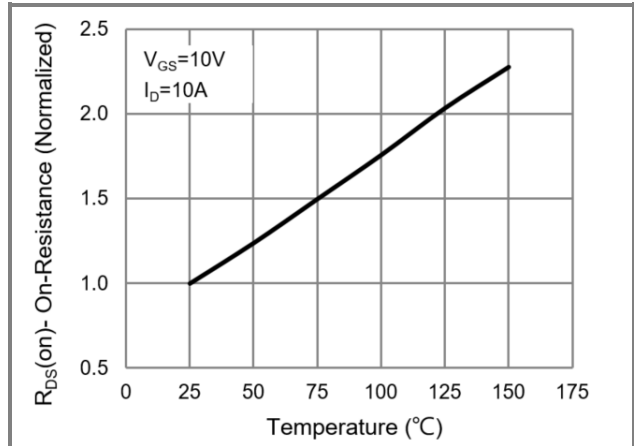


Fig.4 On-Resistance vs. Junction Temperature

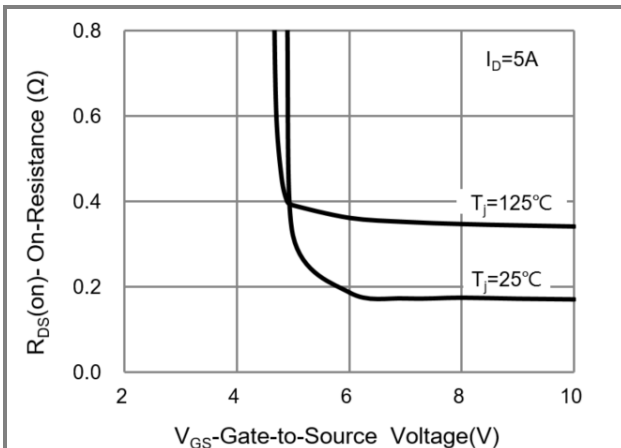


Fig.5 On-Resistance Variation with VGS

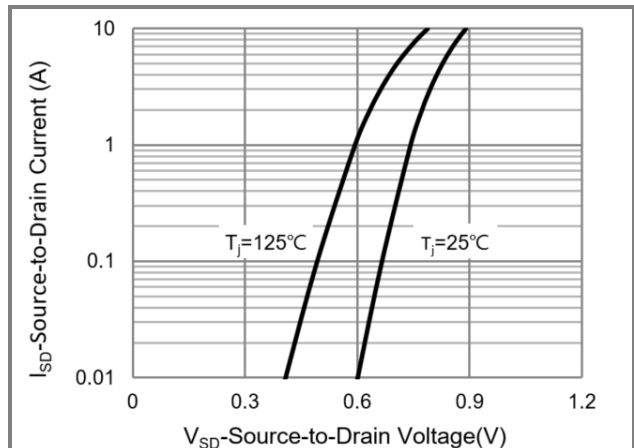


Fig.6 Source-Drain Diode Forward Voltage



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## TYPICAL CHARACTERISTIC CURVES

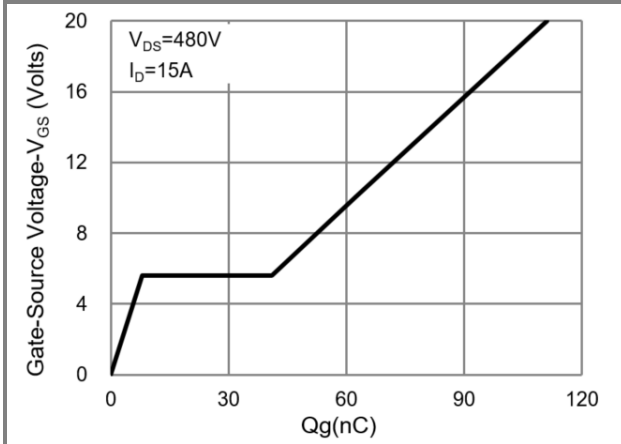


Fig.7 Gate-Charge Characteristics

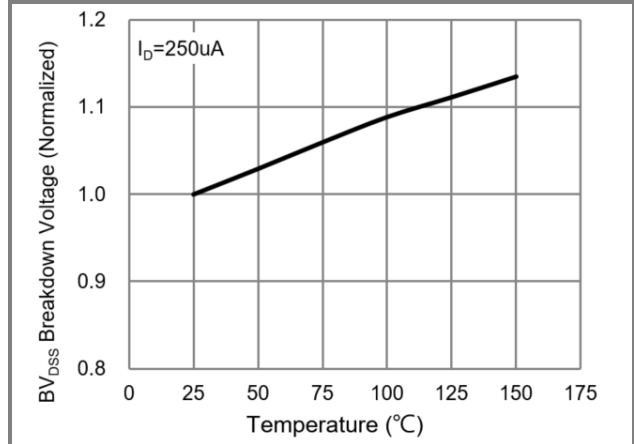


Fig.8 Breakdown Voltage Variation vs. Temperature

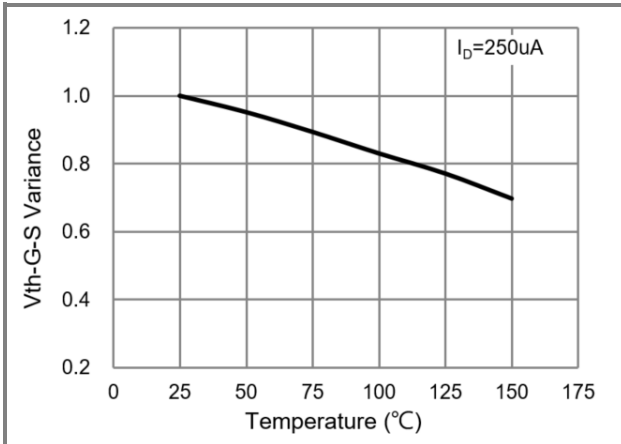


Fig.9 Threshold Voltage Variation with Temperature

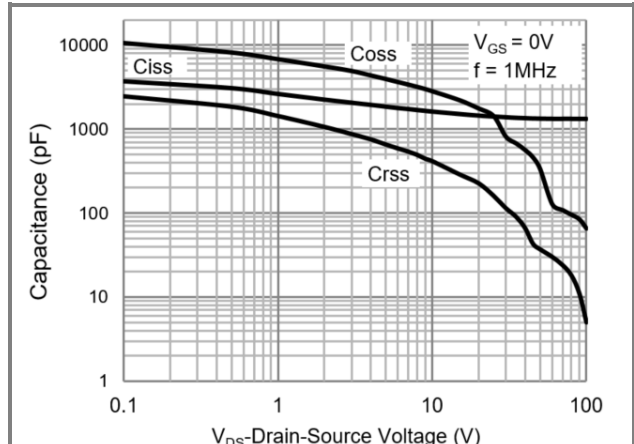


Fig.10 Capacitance vs. Drain-Source Voltage

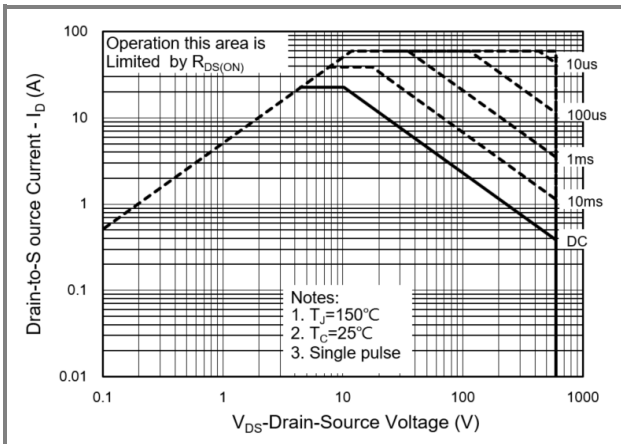


Fig.11 PJP Maximum Safe Operating Area

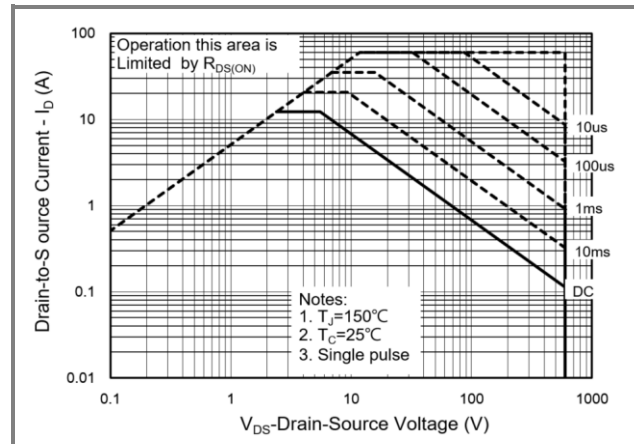


Fig.12 PJF Maximum Safe Operating Area



# PJP60R190E / PJF60R190E

## TYPICAL CHARACTERISTIC CURVES

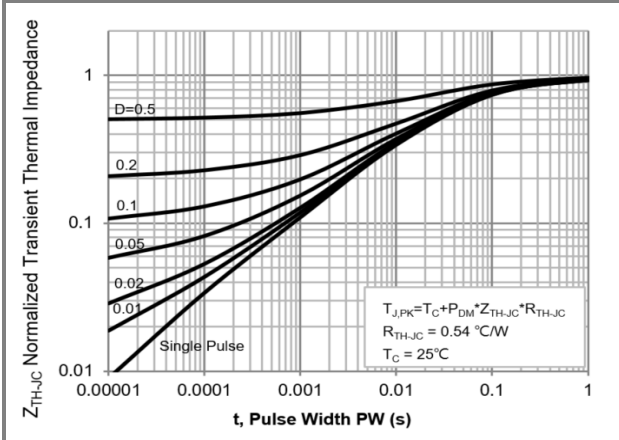


Fig.13 PJP Normalized Transient Thermal Impedance

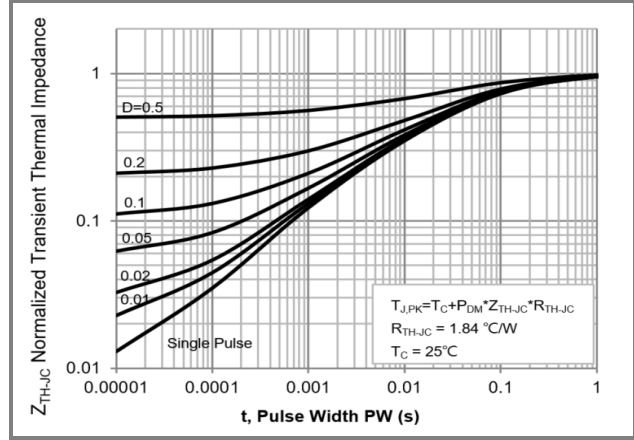


Fig.14 PJF Normalized Transient Thermal Impedance

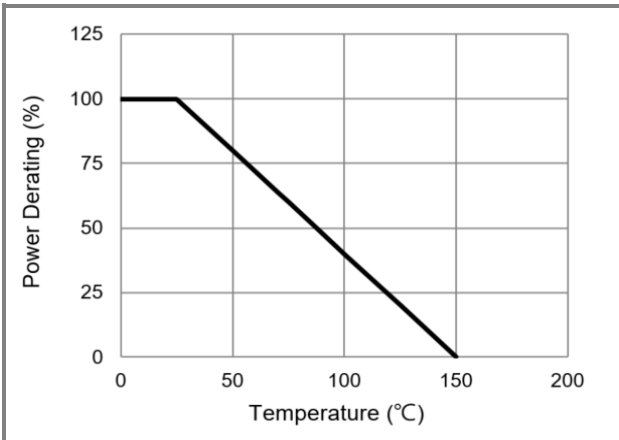
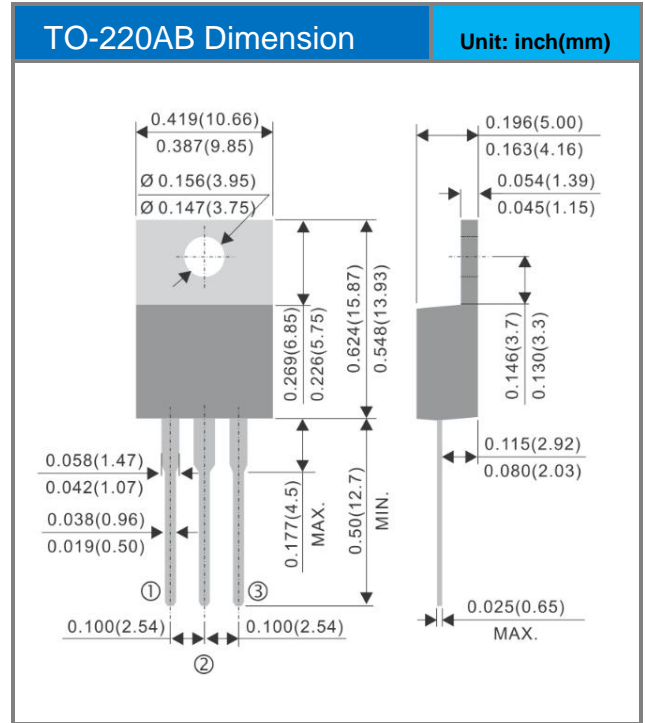
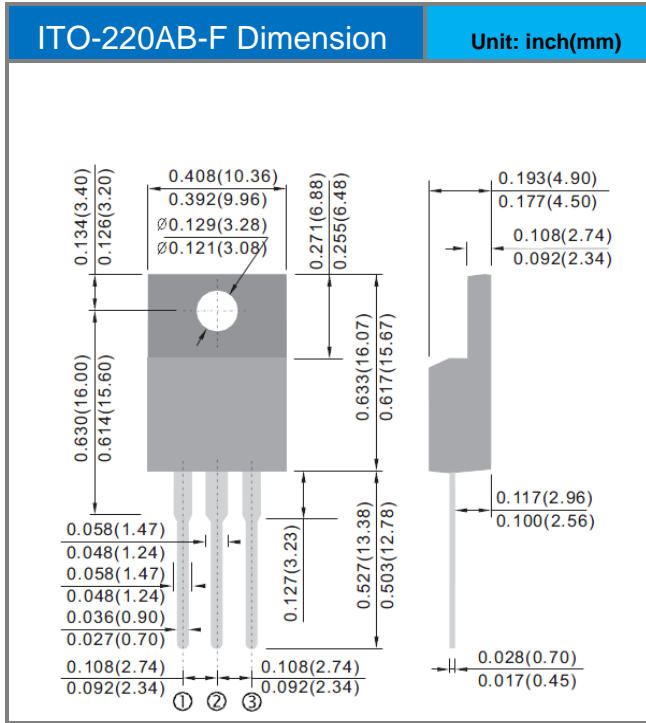


Fig.15 Total Power Dissipation



# PJP60R190E / PJF60R190E

## Packaging Information





## PJP60R190E / PJF60R190E

### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJP60R190E_T0_00001	TO-220AB	50pcs / Tube	60R190E	Halogen free
PJF60R190E_T0_00001	ITO-220AB-F	50pcs / Tube	60R190E	Halogen free



## PJP60R190E / PJF60R190E

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